

2-Line Bi-directional ESD Protection Diode

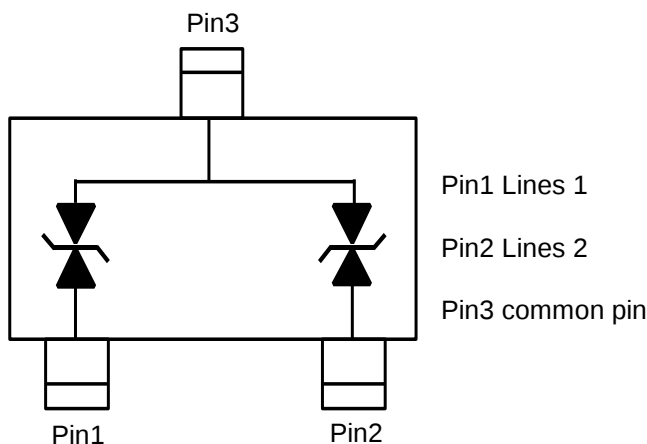
Description

These dual monolithic silicon surge protection diodes are designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment. as computers, printers, business machines, communication systems, medical equipment and other applications. Their bi-directional double ESD design protects two separate lines using only one package. These devices are ideal for situations where board space is at a premium.

Features

- Bi-directional ESD protection of two line
- Reverse stand-off voltage: 36V Max
- Low clamping voltage
- Low leakage current:Na level
- Response time is typically < 1ns
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 - Air discharge: $\pm 30\text{kV}$
 - Contact discharge: $\pm 30\text{kV}$
 - IEC61000-4-5 (Lightning) 7A (8/20 μs)
- RoHS Compliant

Schematic and Pin Configuration



Circuit and Pin Schematic

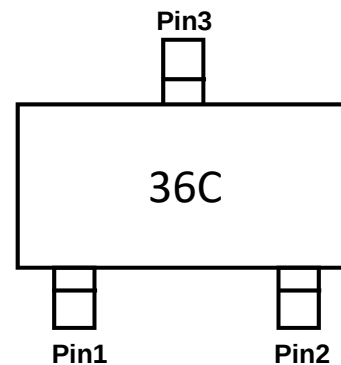
Mechanical Characteristics

- Package: SOT-23
- Case Material: “Green” Molding Compound
- We declare that the material of product compliance with RoHS requirements and Halogen Free

Applications

- Cell Phone Handsets and Accessories
- Portable electronics
- Computers and peripherals
- Communication systems
- Audio and video equipment

Marking Information



36C= Device Marking Code

Ordering Information

Part Number	Shipping	Reel Size
PSM36C	3000/Tape &Reel	7 inch

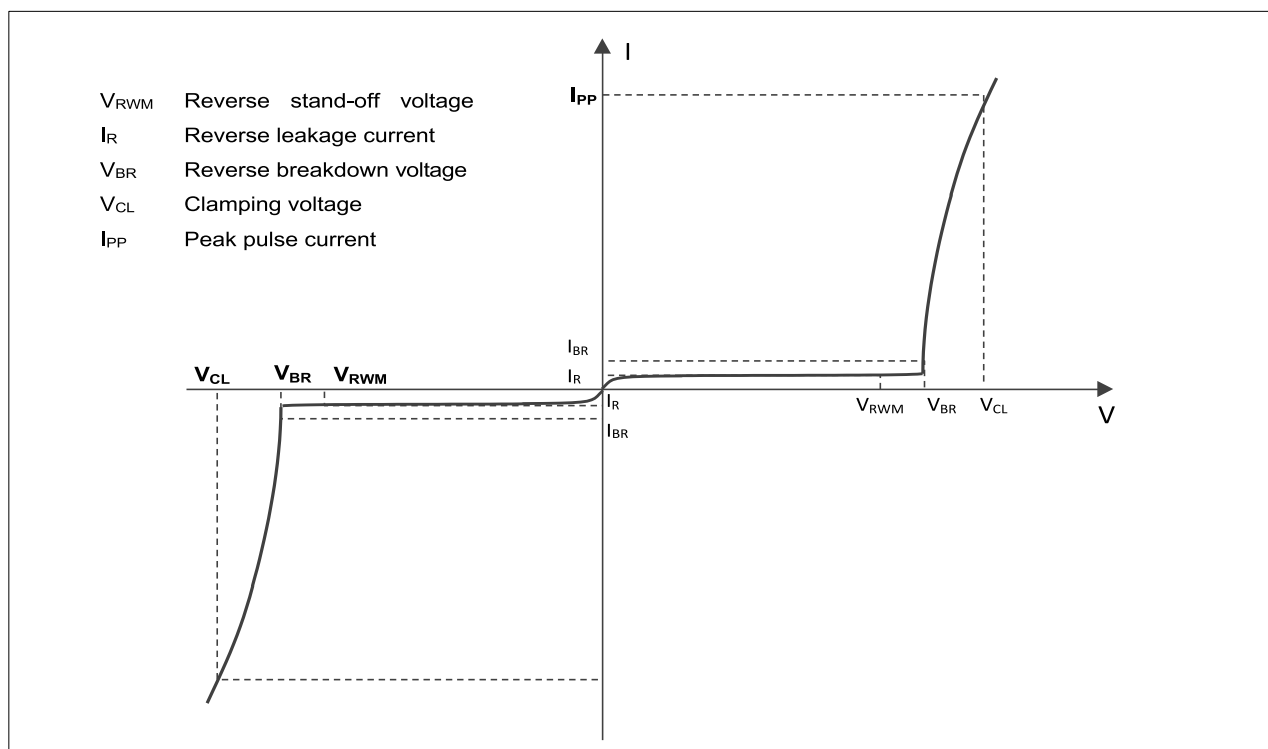
Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 μs)	P_{PK}	420	W
Peak Pulse Current (8/20 μs)	I_{PP}	7	A
ESD per IEC 61000-4-2 (Air)	V_{ESD}	± 30	kV
ESD per IEC 61000-4-2 (Contact)		± 30	kV
Lead temperature	T_L	260	$^{\circ}\text{C}$
Junction Temperature	T_J	125	$^{\circ}\text{C}$
Operating Temperature Range	T_{OP}	$-40 \sim +125$	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$

Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise specified)

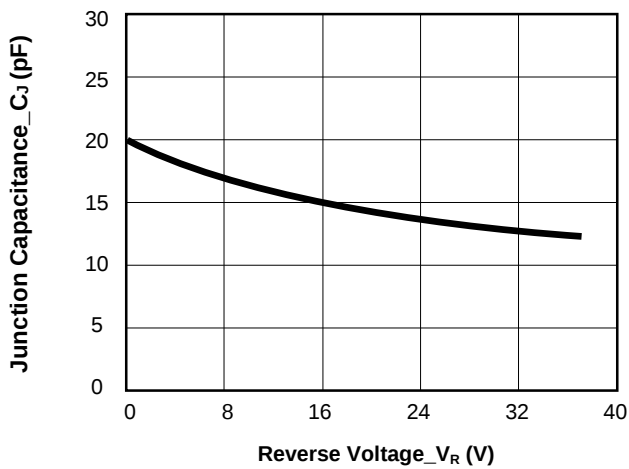
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Condition
Reverse Working Voltage	V_{RWM}			36	V	
Reverse Breakdown Voltage	V_{BR}	39			V	$I_T = 1\text{mA}$
Reverse Leakage Current	I_R			0.1	μA	$V_{RWM} = 36\text{ V}$
Clamping Voltage	V_C			46	V	$I_{PP} = 1\text{A}$ (8/20 μs pulse)
Clamping Voltage	V_C			60	V	$I_{PP} = 7\text{A}$ (8/20 μs pulse)
Junction Capacitance	C_J		20	25	pF	$V_R = 0\text{V}$, $f = 1\text{MHz}$

Electrical characteristics ($T_A = 25^\circ\text{C}$, unless otherwise noted)

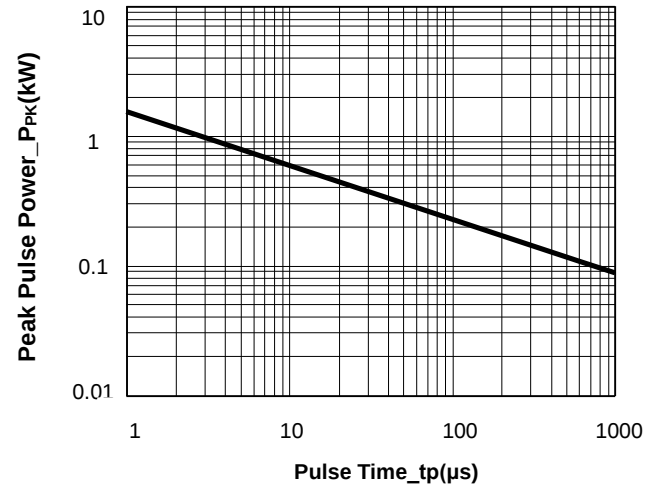


Definitions of electrical characteristics

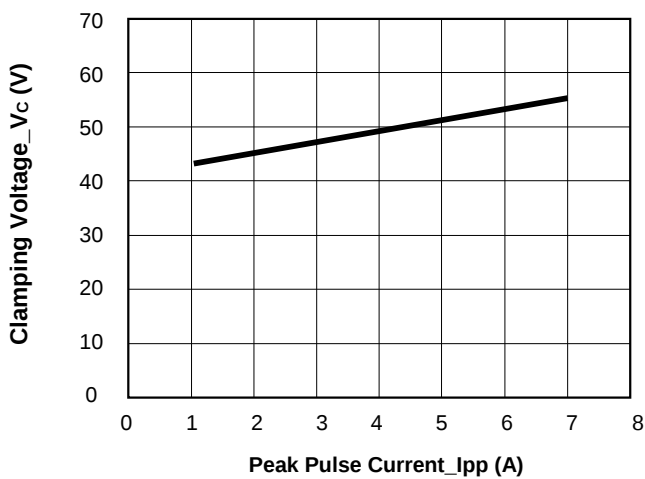
Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)



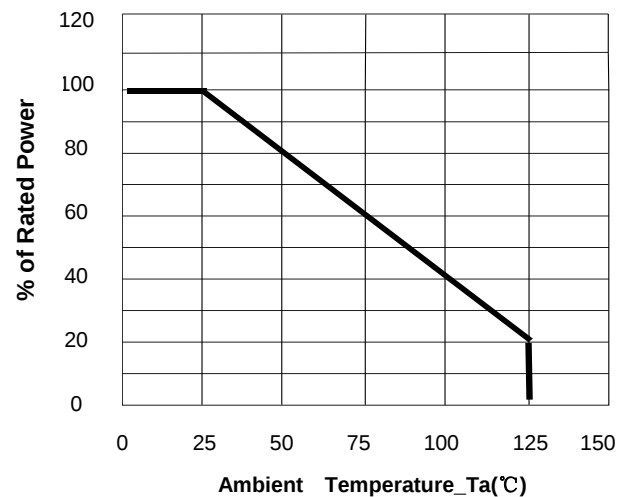
Junction Capacitance vs. Reverse Voltage



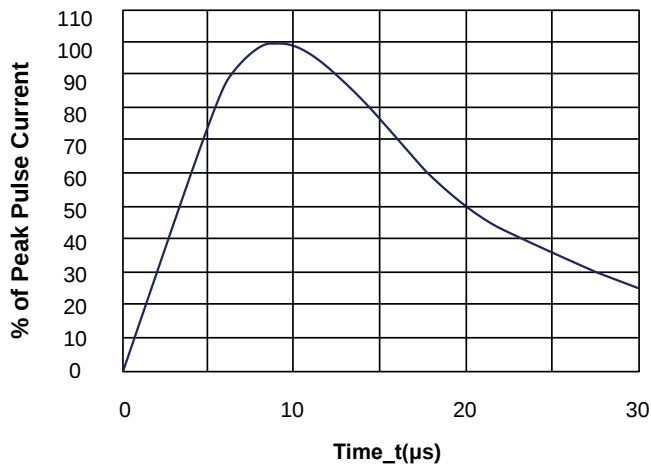
Peak Pulse Power vs. Pulse Time



Clamping Voltage vs. Peak Pulse Current

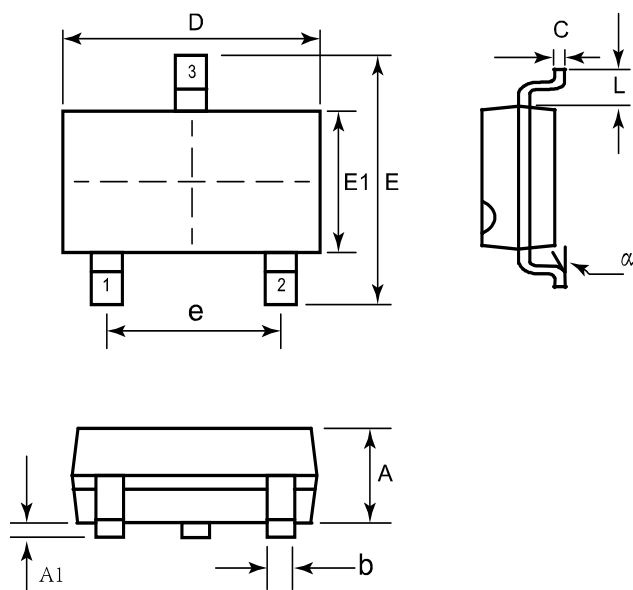


Power Derating Curve



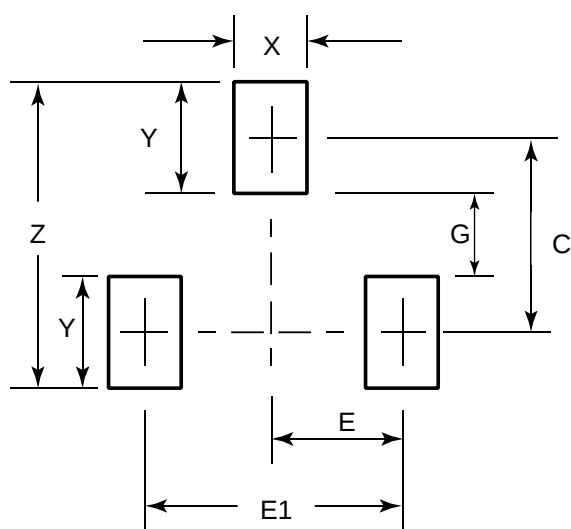
8/20 μs Pulse Waveform

SOT-23 Package Outline Drawing



SYM	DIMENSIONS					
	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.035	0.037	0.040	0.88	0.95	1.02
A1	0.000	-	0.004	0.01	-	0.10
b	0.012	-	0.020	0.30	-	0.51
C	0.003	-	0.007	0.08	-	0.18
D	0.110	0.114	0.120	2.80	2.90	3.04
E	0.082	0.093	0.104	2.10	2.37	2.64
E1	0.047	0.051	0.055	1.20	1.30	1.40
e	0.075 BSC			1.90 BSC		
L	0.022 BSC			0.55 BSC		
α	0°		8°	0°		8°

Suggested Land Pattern



SYM	DIMENSIONS	
	MILLIMETERS	INCHES
C	2.20	0.087
E	0.95	0.037
E1	1.90	0.075
G	0.80	0.031
X	1.00	0.039
Y	1.40	0.055
Z	3.60	0.141

A diagram of a circular ring (annulus) consisting of two concentric circles. The outer circle has a radius of 7 inches, as indicated by a dimension line and the label "7 inch" on the right side of the diagram.

Technical drawing of a mechanical part showing dimensions and tolerances. The drawing includes a top view and a side view. The top view shows a rectangular plate with six circular holes. The side view shows the thickness of the plate and the positions of the holes. Dimensions and tolerances are indicated as follows:

- Top view dimensions:
 - Distance between the first and second holes: 4.00 ± 0.10
 - Distance between the second and third holes: 2.00 ± 0.10
 - Distance between the fourth and fifth holes: 4.00 ± 0.10
 - Hole diameter: $\Phi 1.50 \pm 0.10$
- Side view dimensions:
 - Distance from the top surface to the center of the holes: 1.75 ± 0.10
 - Distance from the bottom surface to the center of the holes: 8.00 ± 0.10
 - Distance from the top surface to the bottom surface: 3.50 ± 0.10

A diagram of a rectangular table with a wavy edge on the left and right sides. In the center of the table is a circle. On the left side of the table is a square table labeled "36C". On the right side of the table is another square table labeled "36C".



User Direction of Feed

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